SERIAL NUMBER	<u>.</u>	FILING DATE	CLASS	GROUP ART UNIT	ATTORNEY D	OCKET NO.
09/352,1	94	07/13/99	257	2811	0756-19	98
SHUNPEI YA	MAZAKI, TOP NAGAWA, JAI	KYO, JAPAN; H	ISASHI OHTAN	I, KANAGAWA, JA	PAN; TAMAE	
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UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Dox 1450 Alexandris, Viginia 22313-1450 www.mpto.gov



Bib Data Sheet

CONFIRMATION NO. 1911

SERIAL NUMBER 09/352,194	FILING OR 371(c) DATE 07/13/1999 RULE	. c	CLASS 438	GRO	GROUP ART UNIT 2823		ATTORNEY DOCKET NO. 0756-1998						
APPLICANTS				• 1									
SHUNPEI YAMAZAKI, TOKYO, JAPAN; HISASHI OHTANI, KANAGAWA, JAPAN; TAMAE TAKANO, KANAGAWA, JAPAN;													
** CONTINUING DATA **********************************													
** FOREIGN APPLICATIONS *************													
JAPAN 10-203205 07/17/1998 JAPAN 11-135054 05/14/1999													
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IF REQUIRED, FOREIGN FILING LICENSE GRANTED ** 08/05/1999													
Foreign Priority claimed yes no STATE OR SHEETS TOTAL INDEPENDENT													
35 USC 119 (a-d) conditi met Verified and	DRAWING CLA		TOTA CLAII 18	MS	INDEPENDENT CLAIMS 8								
Acknowledged Examiner's Signature Initial's ADDRESS 31780													
TITLE CRYSTALLINE SEMICONDUCTOR THIN FILM, METHOD OF FABRICATING THE SAME, SEMICONDUCTOR DEVICE, AND METHOD OF FABRICATING THE SAME													
		All Fees											
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